

Silicon Carbide Schottky Barrier Diode

V _{RRM}	1200 V	I _F	10 A
V _{F(Typ.)}	1.5 V	Q _c	42 nC

Features

- Temperature Independent Switching Behavior
- High Surge Current Capability
- Positive Temperature Coefficient on V_F
- Low Conduction Loss
- Zero Reverse Recovery
- High junction temperature 175 °C
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

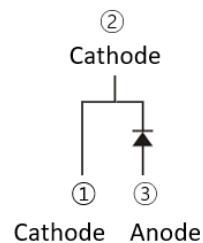
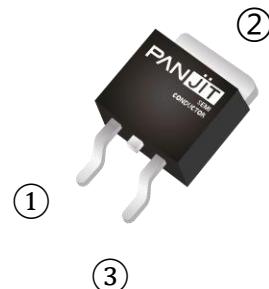
Mechanical Data

- Case: TO-252AA molded plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0113 ounces, 0.3217 grams

Application

- PFC, UPS, PV Inverter, EV Charging Station, Welder

TO-252AA



Maximum Ratings and Thermal Characteristics (T_C = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	LIMIT	UNITS
Repetitive Peak Reverse Voltage	V _{RRM}	1200	V
DC Blocking Voltage	V _{DC}	1200	V
Continuous forward current	I _F	10	A
Repetitive Peak Surge Current <i>Half Sine Wave, D=0.1</i>	I _{FRM}	44 40	A
Peak Forward Surge Current <i>Half Sine Wave</i>	I _{FSM}	72 64	A
Peak Forward Surge Current <i>t_p = 10us, Pulse</i>		640	A
Maximum Power Dissipation	P _{total}	200	W
Operating Junction Temperature Range	T _J	-55~175	°C
Storage Temperature Range	T _{STG}	-55~175	°C

Electrical Characteristics ($T_C = 25^\circ C$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Forward voltage drop	V_F	$I_F = 10 A, T_J = 25^\circ C$	-	1.5	1.7	V
		$I_F = 10 A, T_J = 175^\circ C$	-	2.0	-	
Reverse leakage current	I_R	$V_R = 1200 V, T_J = 25^\circ C$	-	6	100	μA
		$V_R = 1200 V, T_J = 175^\circ C$	-	0.04	-	mA
Total Capacitive Charge	Q_C	$I_F = 10 A, V_R = 800V$	-	42	-	nC
Total Capacitance	C	$V_R = 1V, f = 1MHz$	-	529	-	pF
		$V_R = 400V, f = 1MHz$	-	36	-	pF
		$V_R = 800V, f = 1MHz$	-	25	-	pF
Capacitance Stored Energy	E_C	$V_R = 800V$	-	12	-	μJ
Thermal Resistance	$R_{\theta JC}$		-	0.75	-	$^\circ C/W$

TYPICAL CHARACTERISTIC CURVES

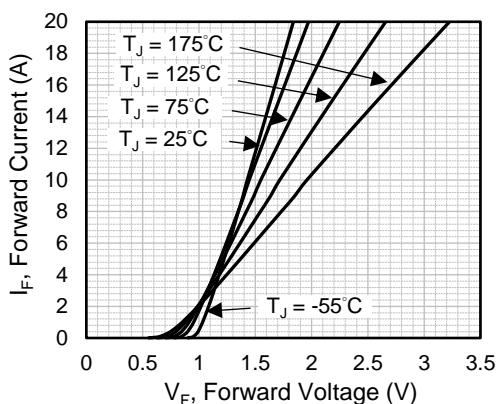


Fig.1 Forward Characteristics

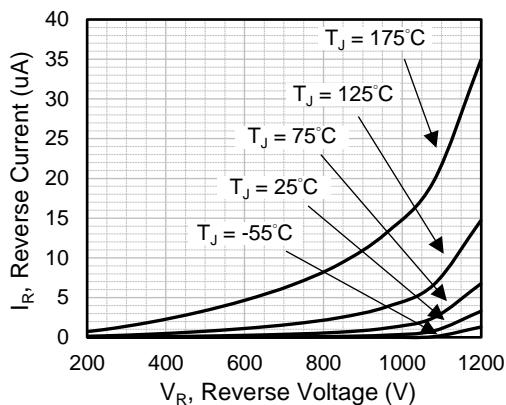


Fig.2 Reverse Characteristics

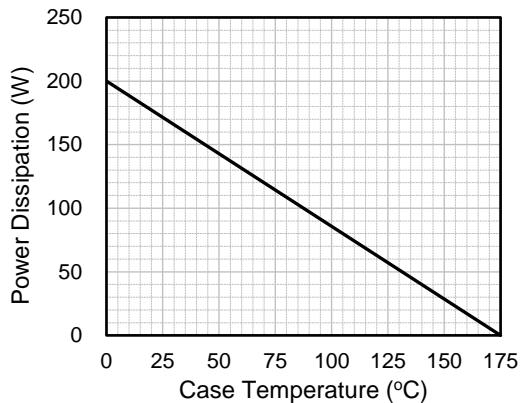


Fig.3 Power Derating Curve

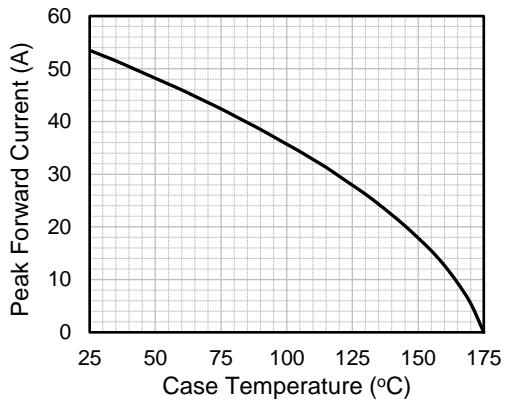


Fig.4 Current Derating Curve

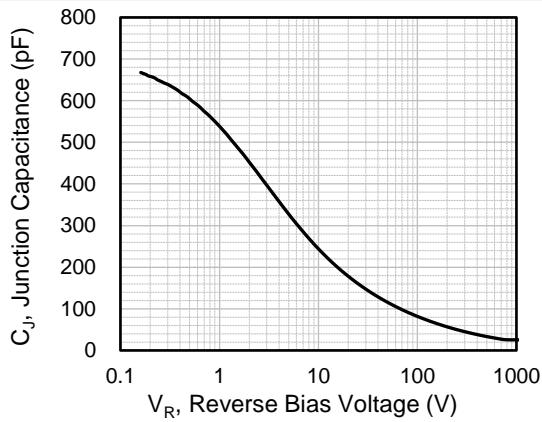


Fig.5 Typical Junction Capacitance

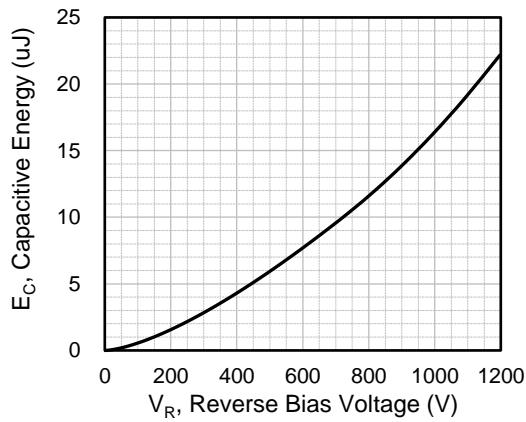
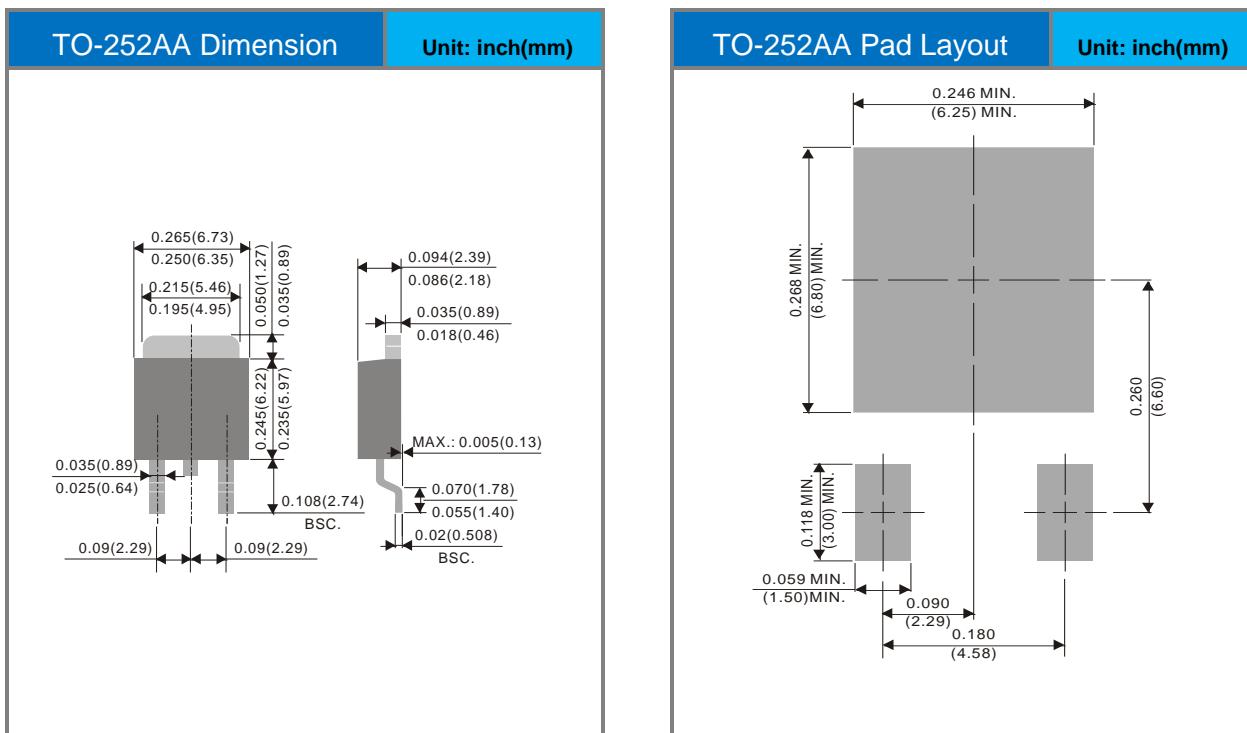


Fig.6 Capacitance Stored Energy

Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PCDD10120G1	TO-252AA	3,000pcs / Reel	CDD10120

Packaging Information & Mounting Pad Layout



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